NSN 5961-00-105-0982

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/iew Online at https://aerobasegroup.com/nsn/5961-00-105-0982

view Online at https://aerobasegroup.com/nsn/5961-00-105-0962
Inclosure Material:
Metal
Overall Length:
0.185 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.370 inches
End Application:
Virginia class cgn (41); spruance class dd (963); los angeles class ssn (688); wasp class lhd; oliver perry class ffg; emory s. Land class
as; nimitz class cvn; sturgeon class ssn (637); iwo jima class lph
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-99
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
30.0 breakdown voltage, collector-to-base, emitter open all transistor and 15.0 breakdown voltage, collector-to-emitter, base open all
transistor and 3.0 emitter to base voltage, static, collector open all transistor
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
550.0 milliwatts small-signal input power, common-collector preset all transistor
Transfer Ratio:
50.0 small-signal short-circuit forward current transfer ratio, common-emitter all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Weapon system essential; transistors junction pattern arrangement is npn
Terminal Type And Quantity:
8 uninsulated wire lead
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

No

Fiig:

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